ACTT4S-800ETN

AC Thyristor Triac power switch

Rev.02 - 01 September 2026 Product data sheet

1. General description

AC Thyristor Triac power switch in a DPAK surface mountable plastic package with self-protective clamping capabilities against low and high energy transients. This "series ETN" triac will commutate the full RMS current at the maximum rated junction temperature ($T_{j(max)}$ = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

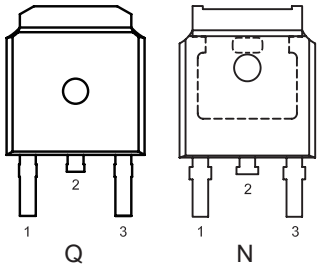
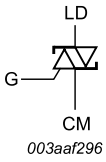
Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{mb} \leq 131$ °C; Fig. 1; Fig. 2; Fig. 3		4	A
I_{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5		40	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms		44	A
T_j	operating junction temperature			-40 to 150	°C

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
I_{GT}	gate trigger current	V_D = 12 V; I_T = 0.1 A; LD+ G+; T_j = 25 °C; Fig. 8		-	-	10	mA
		V_D = 12 V; I_T = 0.1 A; LD+ G-; T_j = 25 °C; Fig. 8		-	-	10	mA
		V_D = 12 V; I_T = 0.1 A; LD- G-; T_j = 25 °C; Fig. 8		-	-	10	mA
I_H	holding current	V_D = 12 V; T_j = 25 °C; Fig. 10		-	-	30	mA
V_T	on-state voltage	I_T = 5 A; T_j = 25 °C; Fig. 11		-	-	1.6	V
V_{CL}	clamping voltage	I_{CL} = 0.1 mA; t_p = 1 ms; T_j = 25 °C		850	-	-	V
Dynamic characteristics							
dV_D/dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; $R_{G(T1)}$ = 220 Ω		500	-	-	V/µs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	CM	common		
2	LD	load		
3	G	gate		
mb	LD	mounting base; load		

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
ACTT4S-800ETN	TO252	ACTT4S-800ETNJ	Reel	2500	TO252N	04-Nov-2016
					TO252Q	05-Mar-2025

7. Marking

Table 4. Marking codes

Type number	Marking codes	
	Assembly factory: N	Assembly factory: Q
ACTT4S-800ETN	ACTT4S 800ETN PJNxxxx xx	ACTT4S 800ETN PJQxxxx xx

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
V_{RRM}	repetitive peak reverse voltage			800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{mb} \leq 131$ °C; Fig. 1; Fig. 2; Fig. 3		4	A
I_{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25$ °C; $t_p = 20$ ms; Fig 4; Fig 5		40	A
		full sine wave; $T_{j(init)} = 25$ °C; $t_p = 16.7$ ms		44	A
I^2t	I^2t for fusing	$t_p = 10$ ms; sine-wave pulse		8	A^2s
dI_T/dt	rate of rise of on-state current	$I_G = 20$ mA		100	A/µs
I_{GM}	peak gate current	$t_p = 20$ µs		4	A
P_{GM}	peak gate power			10	W
$P_{G(AV)}$	average gate power	over any 20 ms period		0.5	W
T_{stg}	storage temperature			-40 to 150	°C
T_j	operating junction temperature			-40 to 150	°C
V_{PP}	peak pulse voltage	$T_j = 25$ °C; non-repetitive off-state; Fig. 6		2	kV

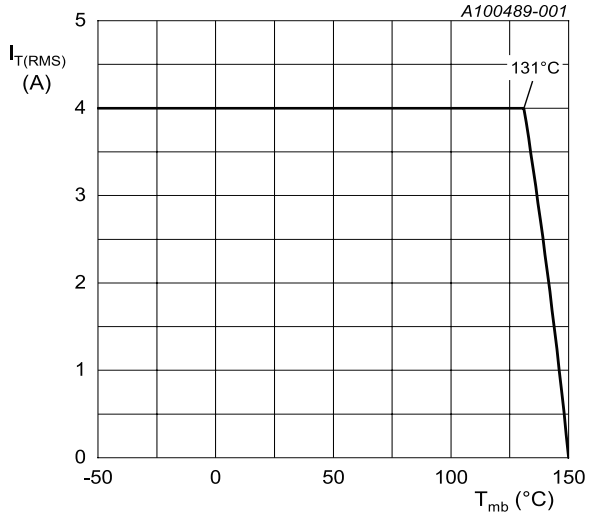
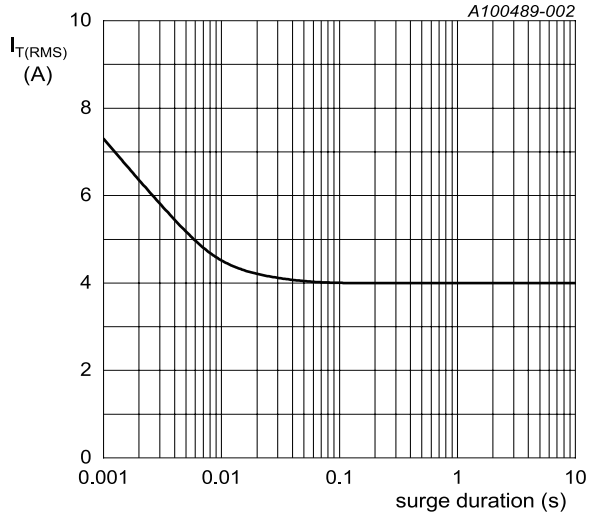


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values



f = 50 Hz; $T_{mb} = 131$ °C

Fig. 2. RMS on-state current as a function of surge duration; maximum values

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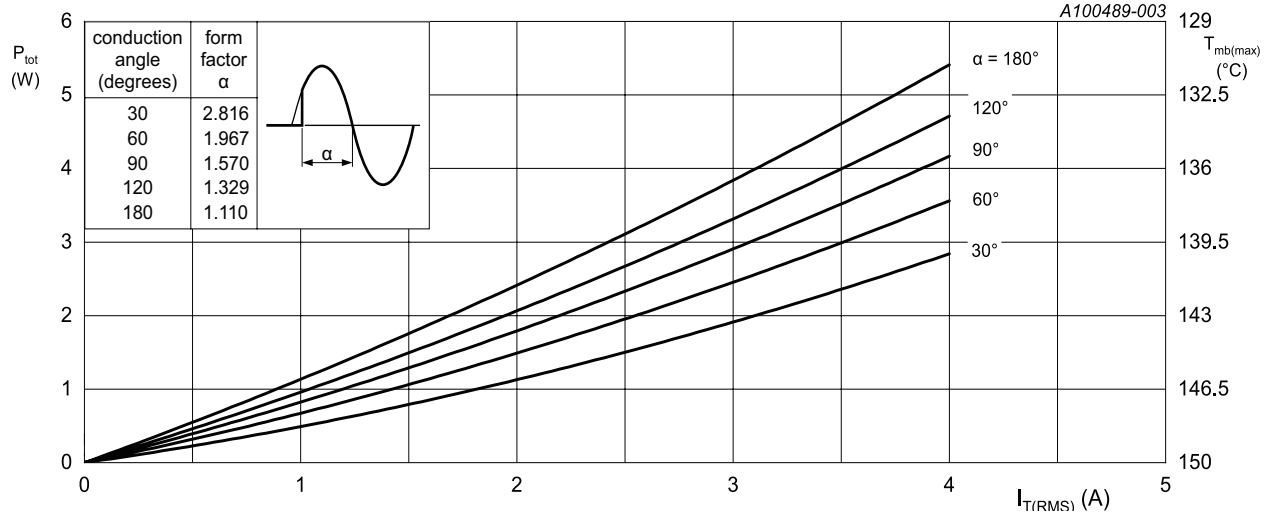
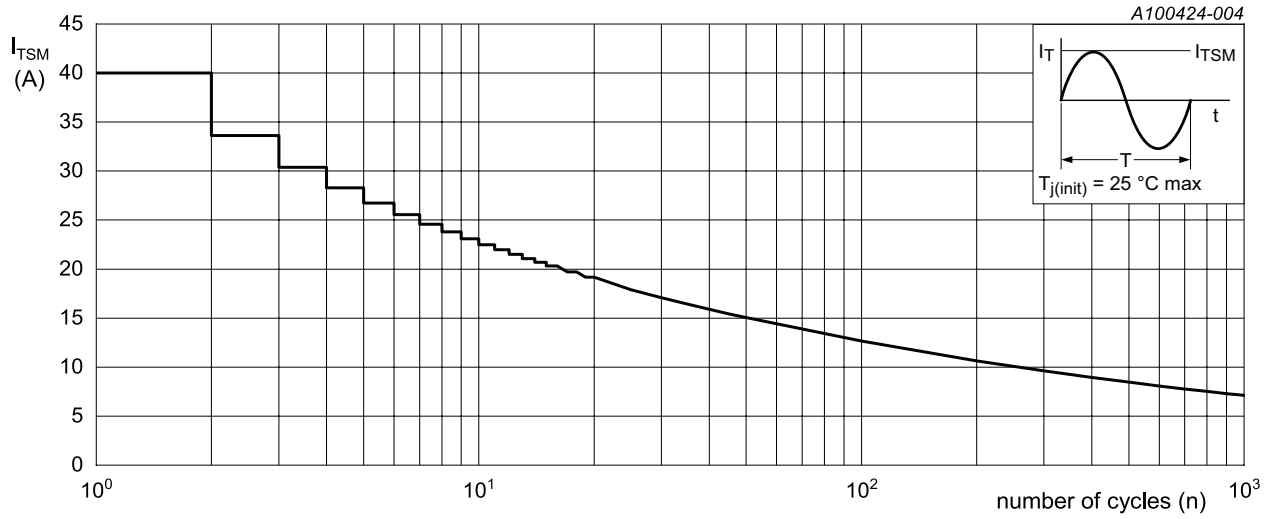


α = conduction angle

a = form factor = $I_{T(RMS)}$ / $I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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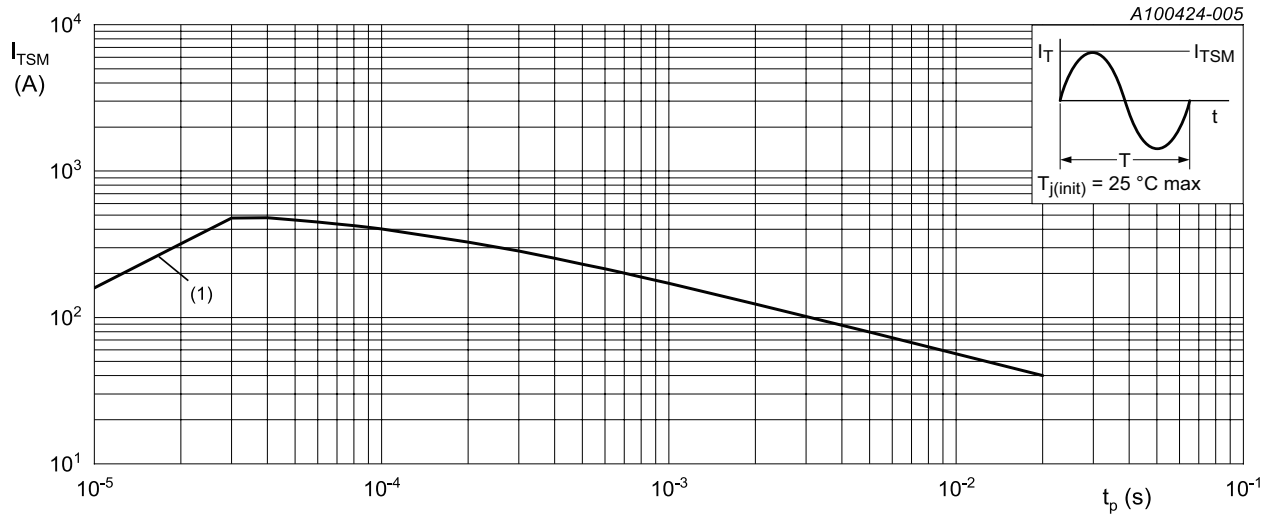

$t_p \leq 20$ ms

(1) dI_T/dt limit

Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

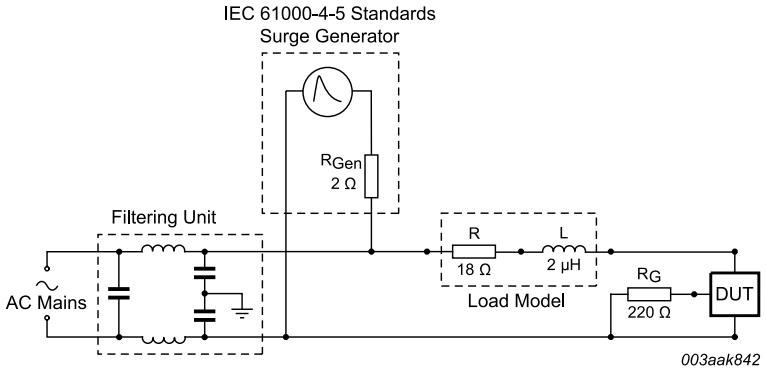

Fig. 6. Test circuit for inductive and resistive loads with conditions equivalent to IEC 61000-4-5

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycle; Fig. 7		-	-	3.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air; printed circuit board (FR4) mounted		-	50	-	K/W

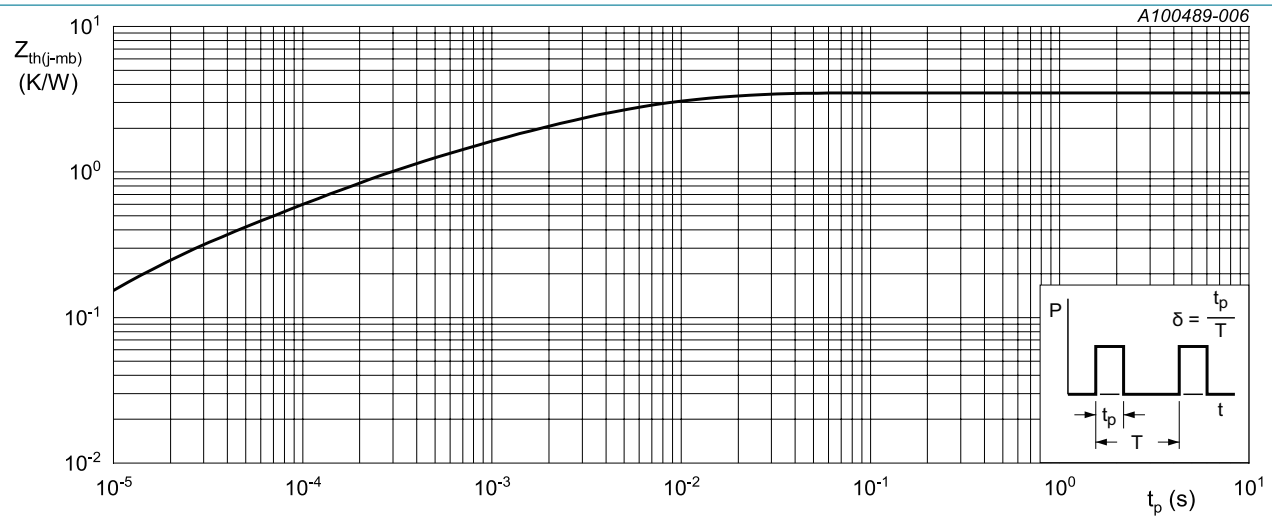

Fig. 7. Transient thermal impedance from junction to mounting base as a function of pulse width

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
I_{GT}	gate trigger current	V_D = 12 V; I_T = 0.1 A; LD+ G+; T_j = 25 °C; Fig. 8		-	-	10	mA
		V_D = 12 V; I_T = 0.1 A; LD+ G-; T_j = 25 °C; Fig. 8		-	-	10	mA
		V_D = 12 V; I_T = 0.1 A; LD- G-; T_j = 25 °C; Fig. 8		-	-	10	mA
I_L	latching current	V_D = 12 V; I_G = 0.1 A; LD+ G+; T_j = 25 °C; Fig. 9		-	-	40	mA
		V_D = 12 V; I_G = 0.1 A; LD+ G-; T_j = 25 °C; Fig. 9		-	-	50	mA
		V_D = 12 V; I_G = 0.1 A; LD- G-; T_j = 25 °C; Fig. 9		-	-	40	mA
I_H	holding current	V_D = 12 V; T_j = 25 °C; Fig. 10		-	-	30	mA
V_T	on-state voltage	I_T = 5 A; T_j = 25 °C; Fig. 11		-	-	1.6	V
V_{GT}	gate trigger voltage	V_D = 12 V; I_T = 0.1 A; T_j = 25 °C; Fig. 12		-	-	1	V
		V_D = 400 V; I_T = 0.1 A; T_j = 150 °C; Fig. 12		0.3	-	-	V
I_D	off-state current	V_D = 800 V; T_j = 25 °C		-	-	10	µA
		V_D = 800 V; T_j = 150 °C		-	-	2	mA
I_R	reverse current	V_R = 800 V; T_j = 25 °C		-	-	10	µA
		V_R = 800 V; T_j = 150 °C		-	-	2	mA
V_{CL}	clamping voltage	I_{CL} = 0.1 mA; t_p = 1 ms; T_j = 25 °C		850	-	-	V
Dynamic characteristics							
dV_D/dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; $R_{G(T1)}$ = 220 Ω		500	-	-	V/µs

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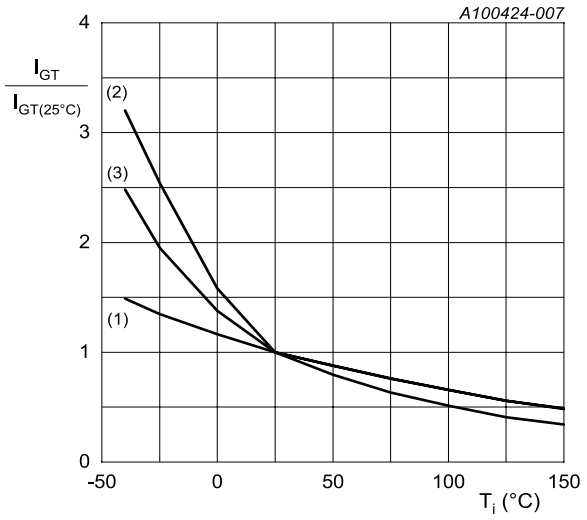


(1) LD+ G+
(2) LD+ G-
(3) LD- G-

Fig. 8. Normalized gate trigger current as a function of junction temperature

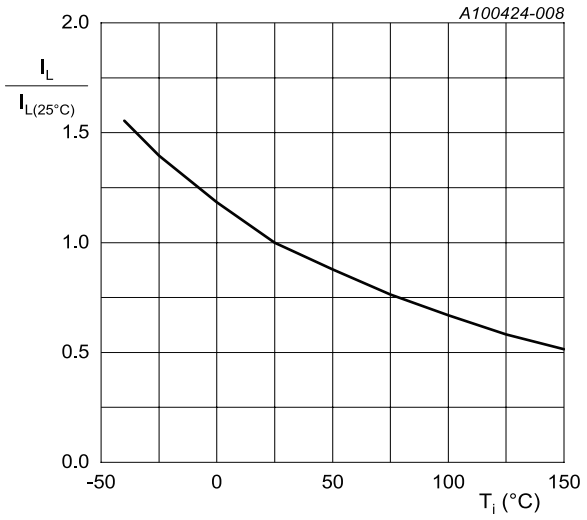


Fig. 9. Normalized latching current as a function of junction temperature

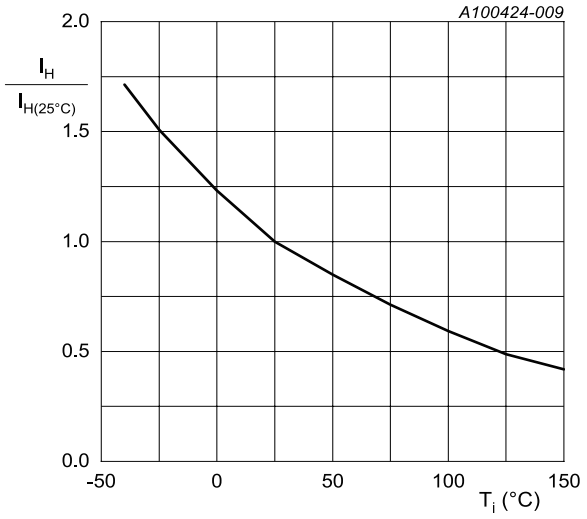
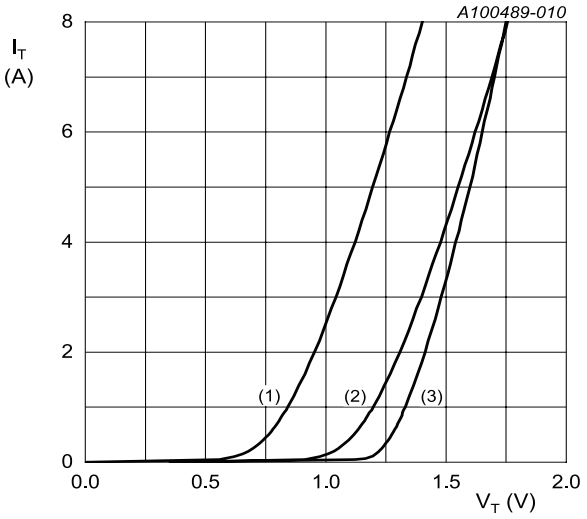


Fig. 10. Normalized holding current as a function of junction temperature



V_o = 1.178 V; R_s = 0.0730 Ω
(1) T_j = 150 °C; typical values
(2) T_j = 150 °C; maximum values
(3) T_j = 25 °C; maximum values

Fig. 11. On-state current as a function of on-state voltage

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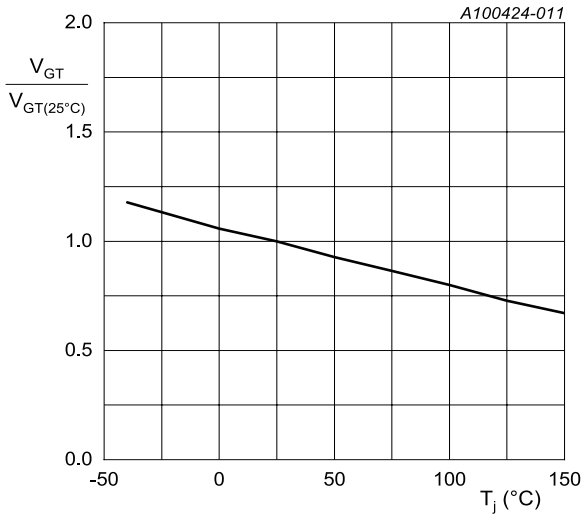

Fig. 12. Normalized gate trigger voltage as a function of junction temperature

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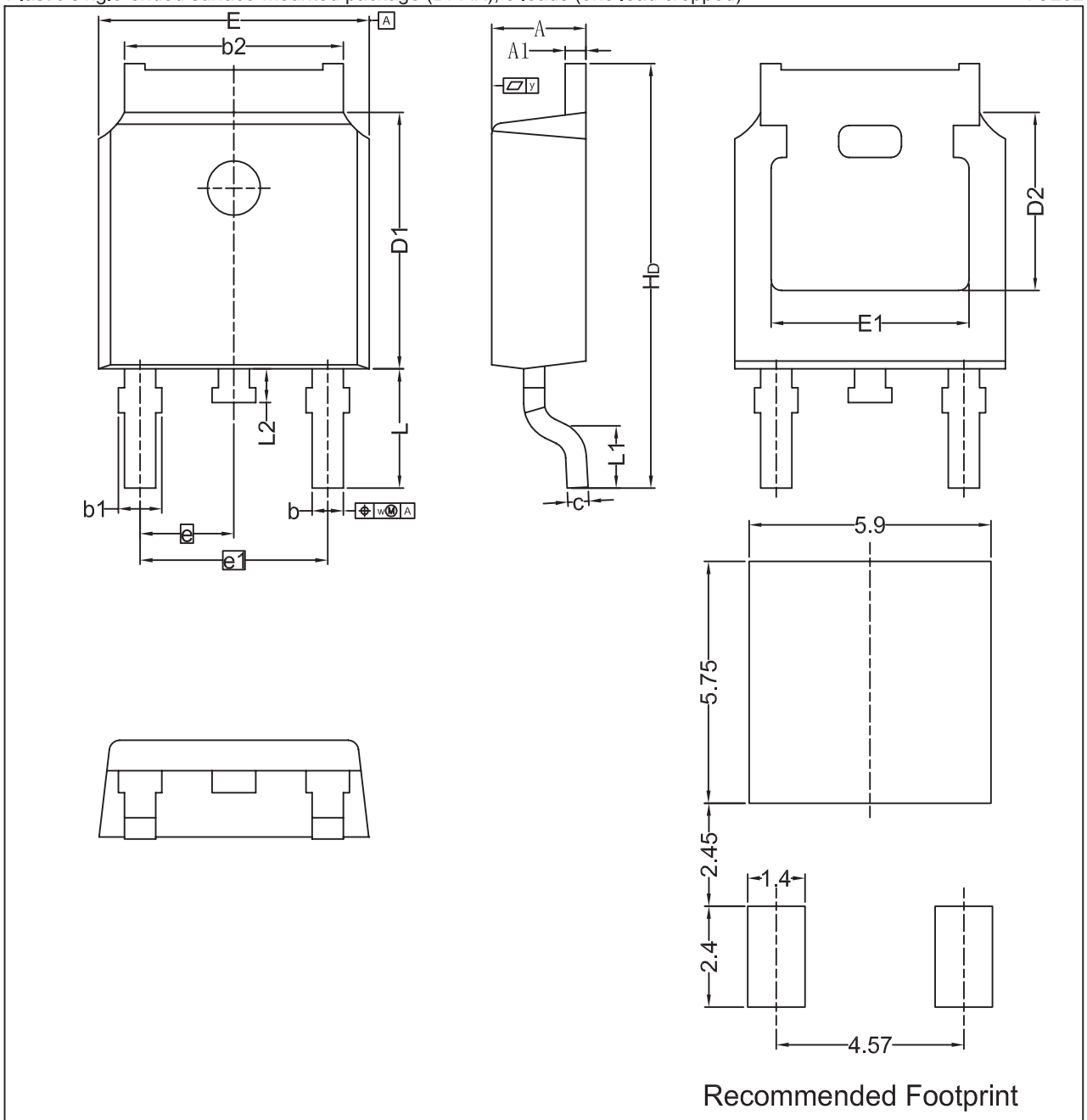
11. Package outline

Assembly factory: N

Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) TO252



Recommended Footprint

Unit	A	A1	b	b1	b2	c	D1	D2	E	E1	e	e1	H_D	L	L1	L2	w	y
min	2.22	0.46	0.71	0.72	5.00	0.20	5.98	4.00	6.47	4.45	2.285	4.57	9.60	2.90 (Ref.)	0.50	0.50	0.20	
mm nom																		
max	2.38	0.93	0.89	1.10	5.46	0.56	6.22	---	6.73	---			10.40		---	0.90		0.20

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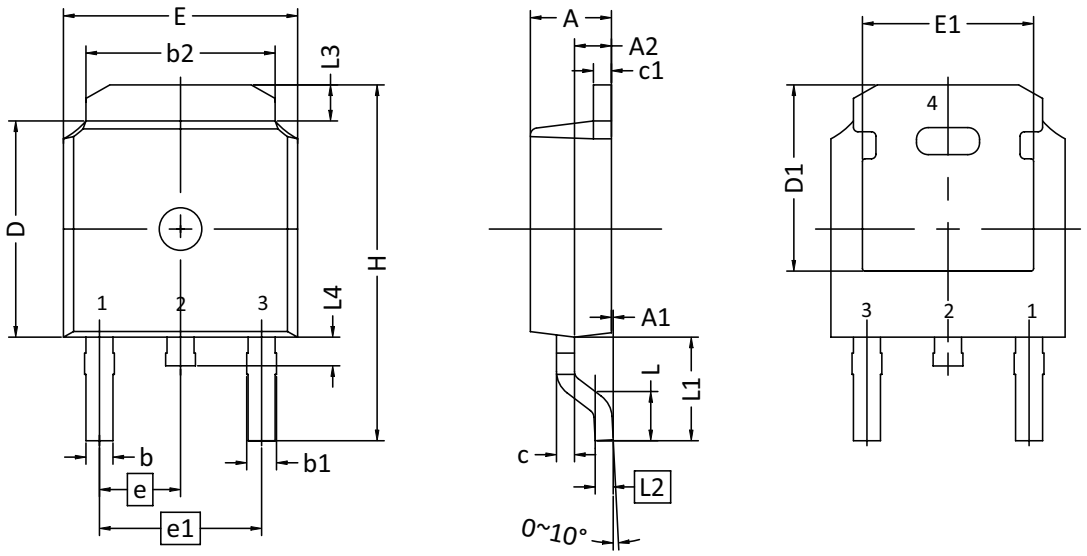
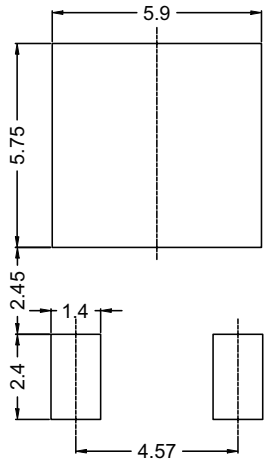
Assembly factory: Q

Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) TO252





Recommended Footprint

SYMBOLS	DIMENSION IN MM		
	MIN	NOM	MAX
A	2.184	2.286	2.400
A1	0.000	---	0.200
A2	0.889	1.041	1.170
b	0.635	0.762	0.889
b1	0.680	0.840	1.143
b2	4.953	5.340	5.500
c	0.450	0.508	0.610
c1	0.450	0.508	0.630
D	5.969	6.096	6.223
D1	5.210	5.249	5.380
E	6.350	6.604	6.800
E1	4.318	4.826	4.920
e	2.286BSC		
e1	4.572BSC		
H	9.398	10.033	10.500
L	1.270	1.520	2.032
L1	2.921REF		
L2	0.408	0.508	0.608
L3	0.889	1.016	1.270
L4	0.600	---	1.016

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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